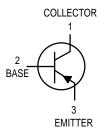
Low Noise Transistors

PNP Silicon







MAXIMUM RATINGS

Rating	Symbol	BC559x	BC560C	Unit	
Collector-Emitter Voltage	VCEO	-30 -45		Vdc	
Collector-Base Voltage	VCBO	-30 -50		Vdc	
Emitter-Base Voltage	VEBO	-5.0		Vdc	
Collector Current — Continuous	IC	-100		mAdc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12		Watt mW/°C	
Operating and Storage Junction Temperature Range	TJ, Tstg	-55 to +150		°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta J A}$	200	°C/W
Thermal Resistance, Junction to Case	R ₀ JC	83.3	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristi	c	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (I _C = -10 mAdc, I _B = 0)	BC559B, C BC560C	V(BR)CEO	-30 -45			Vdc
Collector-Base Breakdown Voltage (I _C = -10μ Adc, I _E = 0)	BC559B, C BC560C	V(BR)CBO	-30 -50			Vdc
Emitter-Base Breakdown Voltage ($I_E = -10 \mu Adc$, $I_C = 0$)		V(BR)EBO	-5.0	_	_	Vdc
Collector Cutoff Current ($V_{CB} = -30$ Vdc, $I_E = 0$) ($V_{CB} = -30$ Vdc, $I_E = 0$, $T_A = +125^{\circ}C$)		ІСВО			15 5.0	nAdc μAdc
Emitter Cutoff Current (V _{EB} = -4.0 Vdc, I _C = 0)		IEBO	—	—	-15	nAdc

replaces BC559/D



BC559B BC559C BC560C

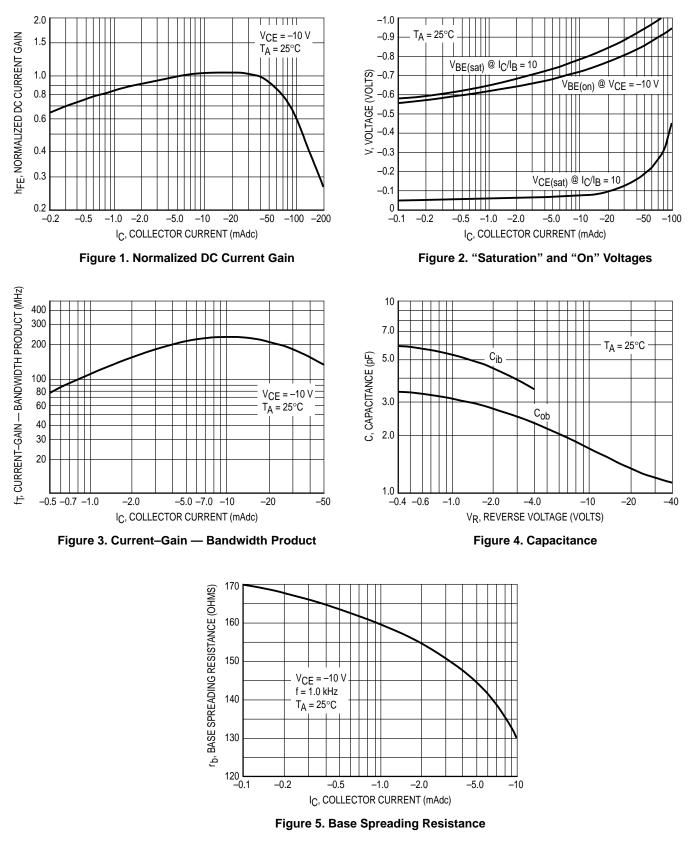
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS	•				
$ \begin{array}{c} \text{DC Current Gain} \\ (I_{C} = -10 \ \mu \text{Adc}, \ V_{CE} = -5.0 \ \text{Vdc}) & \text{BC559B} \\ & \text{BC559C/560C} \\ (I_{C} = -2.0 \ \text{mAdc}, \ V_{CE} = -5.0 \ \text{Vdc}) & \text{BC559B} \\ & \text{BC559B} \\ & \text{BC559C/560C} \end{array} $	hFE	100 100 180 380	150 270 290 500	 460 800	
Collector-Emitter Saturation Voltage ($I_C = -10 \text{ mAdc}, I_B = -0.5 \text{ mAdc}$) ($I_C = -10 \text{ mAdc}, I_B = \text{see note 1}$) ($I_C = -100 \text{ mAdc}, I_B = -5.0 \text{ mAdc}$, see note 2)	V _{CE(sat)}		-0.075 -0.3 -0.25	-0.25 -0.6 	Vdc
Base–Emitter Saturation Voltage ($I_C = -100 \text{ mAdc}, I_B = -5.0 \text{ mAdc}$)	V _{BE(sat)}	_	-1.1	_	Vdc
Base-Emitter On Voltage $(I_C = -10 \ \mu Adc, V_{CE} = -5.0 \ Vdc)$ $(I_C = -100 \ \mu Adc, V_{CE} = -5.0 \ Vdc)$ $(I_C = -2.0 \ mAdc, V_{CE} = -5.0 \ Vdc)$	VBE(on)	 	-0.52 -0.55 -0.62	 	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain — Bandwidth Product ($I_C = -10$ mAdc, $V_{CE} = -5.0$ Vdc, f = 100 MHz)	fT	—	250	—	MHz
Collector–Base Capacitance ($V_{CB} = -10$ Vdc, $I_E = 0$, f = 1.0 MHz)	C _{cbo}	—	2.5	_	pF
Small–Signal Current Gain ($I_C = -2.0 \text{ mAdc}$, $V_{CE} = -5.0 \text{ V}$, f = 1.0 kHz) BC559B BC559C/BC560C	h _{fe}	240 450	330 600	500 900	—
Noise Figure (I _C = -200 μ Adc, V _{CE} = -5.0 Vdc, R _S = 2.0 k Ω , f = 1.0 kHz) (I _C = -200 μ Adc, V _{CE} = -5.0 Vdc, R _S = 100 k Ω , f = 1.0 kHz, Δ f = 200 kHz)	NF ₁ NF ₂		0.5 —	2.0 10	dB

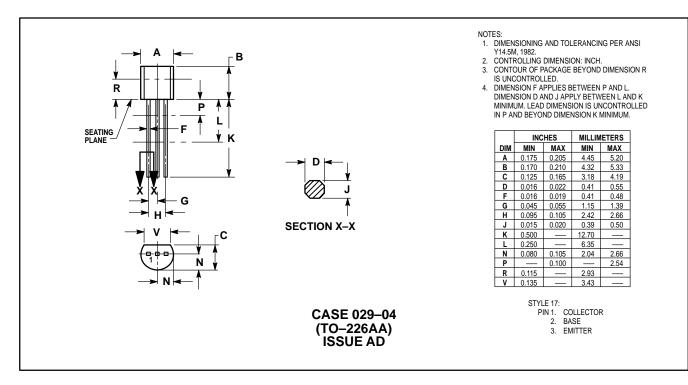
NOTES:

1. IB is value for which IC = -11 mA at VCE = -1.0 V. 2. Pulse test = 300 μ s – Duty cycle = 2%.

BC559B BC559C BC560C



PACKAGE DIMENSIONS



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